

54F/74F175 Quad D Flip-Flop

General Description

The 'F175 is a high-speed quad D flip-flop. The device is useful for general flip-flop requirements where clock and clear inputs are common. The information on the D inputs is stored during the LOW-to-HIGH clock transition. Both true and complemented outputs of each flip-flop are provided. A Master Reset input resets all flip-flops, independent of the Clock or D inputs, LOW.

Features

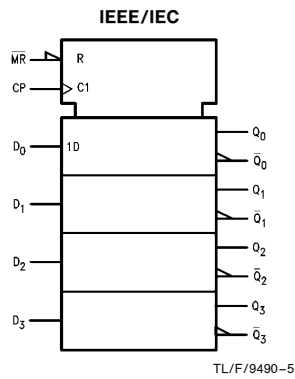
- Edge-triggered D-type inputs
- Buffered positive edge-triggered clock
- Asynchronous common reset
- True and complement output
- Guaranteed 4000V minimum ESD protection

Commercial	Military	Package Number	Package Description
74F175PC		N16E	16-Lead (0.300" Wide) Molded Dual-In-Line
	54F175DM (Note 2)	J16A	16-Lead Ceramic Dual-In-Line
74F175SC (Note 1)		M16A	16-Lead (0.150" Wide) Molded Small Outline, JEDEC
74F175SJ (Note 1)		M16D	16-Lead (0.300" Wide) Molded Small Outline, EIAJ
	54F175FM (Note 2)	W16A	16-Lead Cerpack
	54F175LM (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

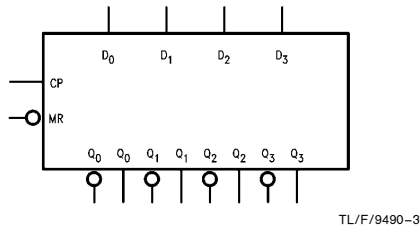
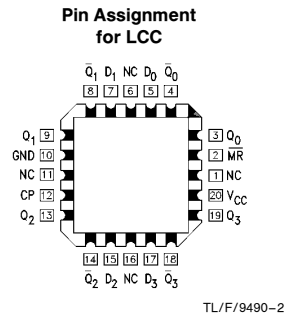
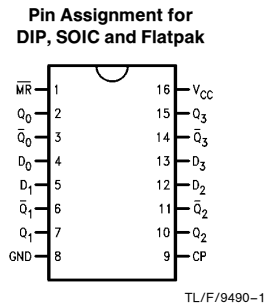
Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB.

Logic Symbols



Connection Diagrams



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Unit Loading/Fan Out


Pin Names	Description	54F/74F	
		U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
D_0-D_3	Data Inputs	1.0/1.0	$20 \mu A / -0.6 \text{ mA}$
CP	Clock Pulse Input (Active Rising Edge)	1.0/1.0	$20 \mu A / -0.6 \text{ mA}$
\overline{MR}	Master Reset Input (Active LOW)	1.0/1.0	$20 \mu A / -0.6 \text{ mA}$
Q_0-Q_3	True Outputs	50/33.3	$-1 \text{ mA} / 20 \text{ mA}$
$\overline{Q_0}-\overline{Q_3}$	Complement Outputs	50/33.3	$-1 \text{ mA} / 20 \text{ mA}$

Functional Description

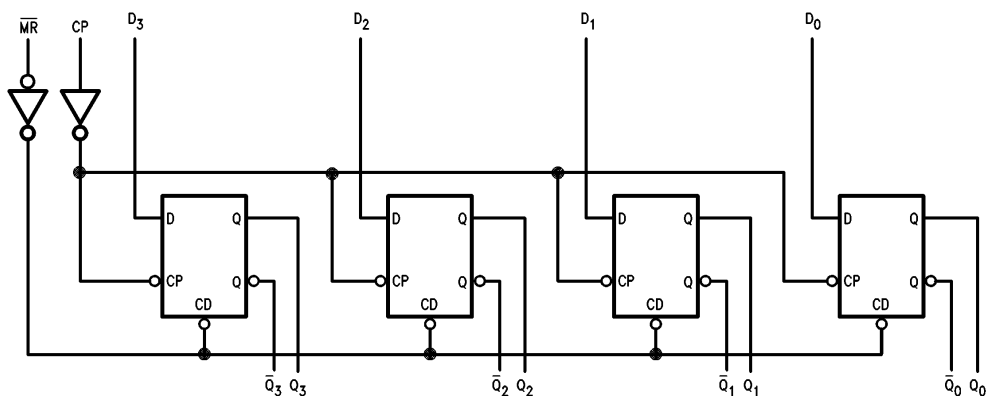
The 'F175 consists of four edge-triggered D flip-flops with individual D inputs and Q and \overline{Q} outputs. The Clock and Master Reset are common. The four flip-flops will store the state of their individual D inputs on the LOW-to-HIGH clock (CP) transition, causing individual Q and \overline{Q} outputs to follow. A LOW input on the Master Reset (\overline{MR}) will force all Q outputs LOW and \overline{Q} outputs HIGH independent of Clock or Data inputs. The 'F175 is useful for general logic applications where a common Master Reset and Clock are acceptable.

Truth Table

Inputs			Outputs	
\overline{MR}	CP	D_n	Q_n	\overline{Q}_n
L	X	X	L	H
H		H	H	L
H		L	L	H

H = HIGH Voltage Level
 L = LOW Voltage Level
 X = Immaterial
 = LOW-to-HIGH Clock Transition

Logic Diagram



TL/F/9490-4

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature	-65°C to +150°C
Ambient Temperature under Bias	-55°C to +125°C
Junction Temperature under Bias	-55°C to +175°C
Plastic	-55°C to +150°C
V _{CC} Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V _{CC} = 0V)	
Standard Output	-0.5V to V _{CC}
TRI-STATE® Output	-0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated I _{OL} (mA)


Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	-55°C to +125°C
Commercial	0°C to +70°C
Supply Voltage	
Military	+4.5V to +5.5V
Commercial	+4.5V to +5.5V

DC Electrical Characteristics

Symbol	Parameter	54F/74F			Units	V _{CC}	Conditions
		Min	Typ	Max			
V _{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V _{CD}	Input Clamp Diode Voltage			-1.2	V	Min	I _{IN} = -18 mA
V _{OH}	Output HIGH Voltage	54F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC}	2.5 2.5 2.7		V	Min	I _{OH} = -1 mA I _{OH} = -1 mA I _{OH} = -1 mA
V _{OL}	Output LOW Voltage	54F 10% V _{CC} 74F 10% V _{CC}		0.5 0.5	V	Min	I _{OL} = 20 mA I _{OL} = 20 mA
I _{IH}	Input HIGH Current	54F 74F		20.0 5.0	μA	Max	V _{IN} = 2.7V
I _{BVI}	Input HIGH Current Breakdown Test	54F 74F		100 7.0	μA	Max	V _{IN} = 7.0V
I _{CEX}	Output HIGH Leakage Current	54F 74F		250 50	μA	Max	V _{OUT} = V _{CC}
V _{ID}	Input Leakage Test	74F	4.75		V	0.0	I _{ID} = 1.9 μA All Other Pins Grounded
I _{OD}	Output Leakage Circuit Current	74F		3.75	μA	0.0	V _{ID} = 150 mV All Other Pins Grounded
I _{IL}	Input LOW Current			-0.6	mA	Max	V _{IN} = 0.5V
I _{OS}	Output Short-Circuit Current			-60	mA	Max	V _{OUT} = 0V
I _{CC}	Power Supply Current		22.5	34.0	mA	Max	CP =  D _n = \overline{MR} = HIGH

AC Electrical Characteristics

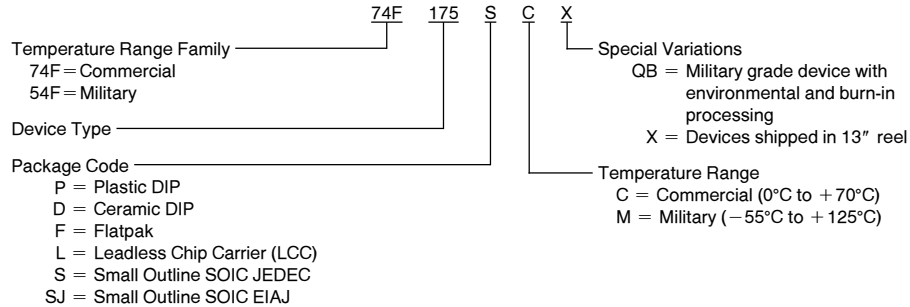
Symbol	Parameter	74F			54F		74F		Units
		T _A = +25°C V _{CC} = +5.0V C _L = 50 pF			T _A , V _{CC} = Mil C _L = 50 pF		T _A , V _{CC} = Com C _L = 50 pF		
		Min	Typ	Max	Min	Max	Min	Max	
f _{max}	Maximum Clock Frequency	100	140		80		100		MHz
t _{PLH} t _{PHL}	Propagation Delay CP to Q _n or \overline{Q}_n	4.0	5.0	6.5	3.5	8.5	4.0	7.5	ns
		4.0	6.5	8.5	4.0	10.5	4.0	9.5	
t _{PHL}	Propagation Delay \overline{MR} to Q _n	4.5	9.0	11.5	4.5	15.0	4.5	13.0	ns
t _{PLH}	Propagation Delay MR to Q _n	4.0	6.5	8.0	4.0	10.0	4.0	9.0	ns

AC Operating Requirements

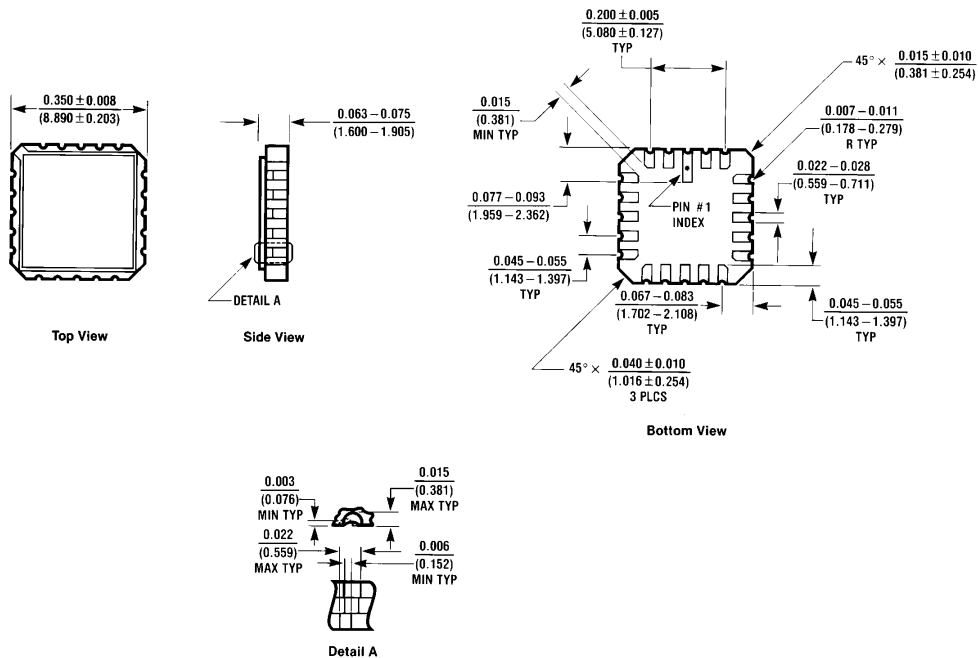
Symbol	Parameter	74F		54F		74F		Units
		T _A = +25°C V _{CC} = +5.0V		T _A , V _{CC} = Mil		T _A , V _{CC} = Com		
		Min	Max	Min	Max	Min	Max	
t _s (H) t _s (L)	Setup Time, HIGH or LOW D _n to CP	3.0		3.0		3.0		ns
		3.0		3.0		3.0		
t _h (H) t _h (L)	Hold Time, HIGH or LOW D _n to CP	1.0		1.0		1.0		ns
		1.0		2.0		1.0		
t _w (H) t _w (L)	CP Pulse Width HIGH or LOW	4.0		4.0		4.0		ns
		5.0		5.0		5.0		
t _w (L)	\overline{MR} Pulse Width, LOW	5.0		5.0		5.0		ns
t _{rec}	Recovery Time, \overline{MR} to CP	5.0		5.0		5.0		ns

Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



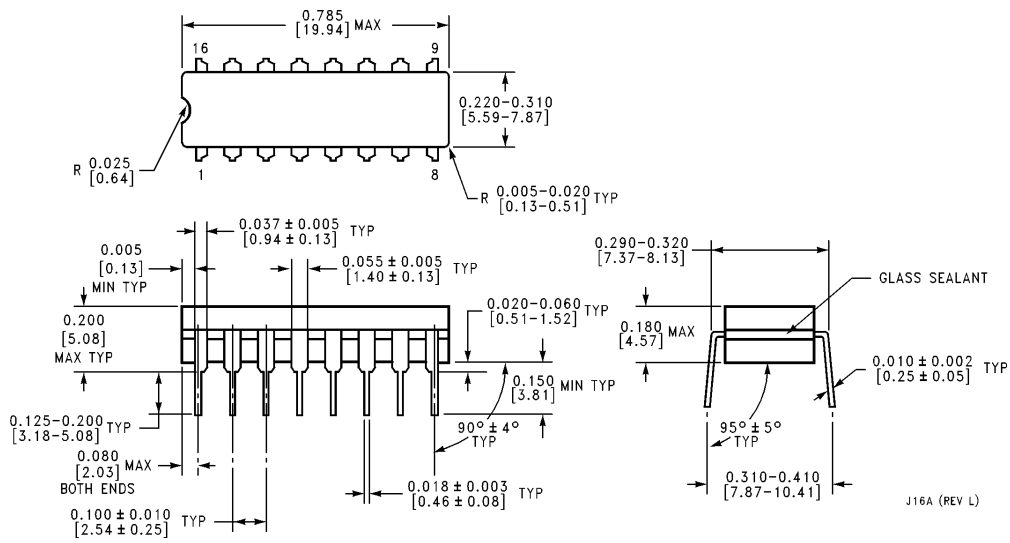
Physical Dimensions inches (millimeters)



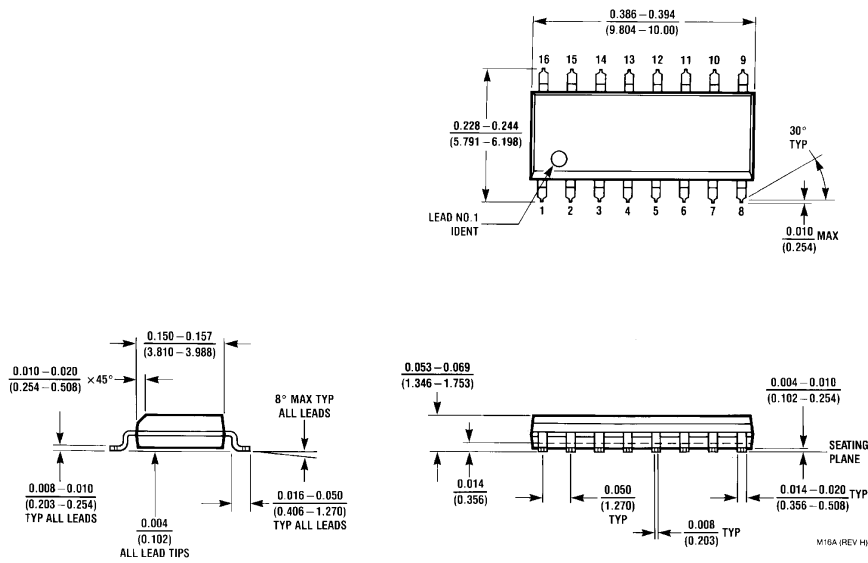
20-Terminal Ceramic Leadless Chip Carrier (L)
NS Package Number E20A

E20A (REV. 0)

Physical Dimensions inches (millimeters) (Continued)

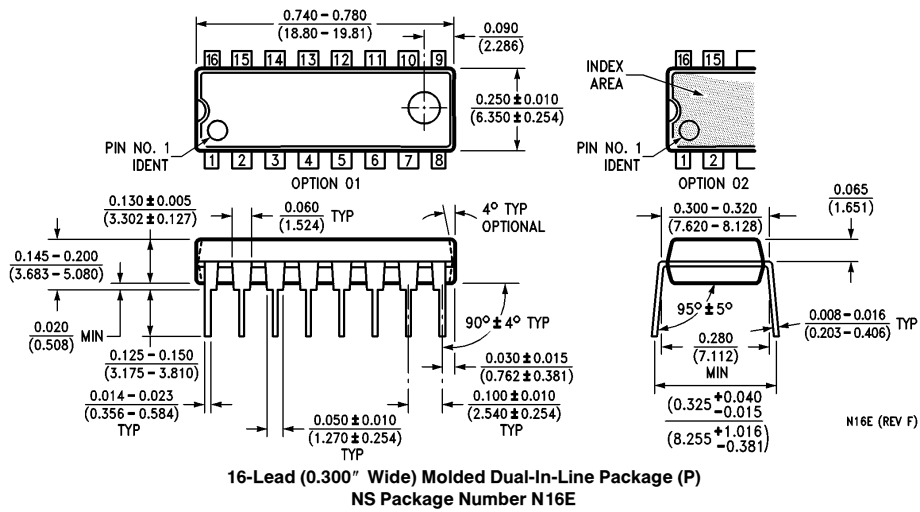
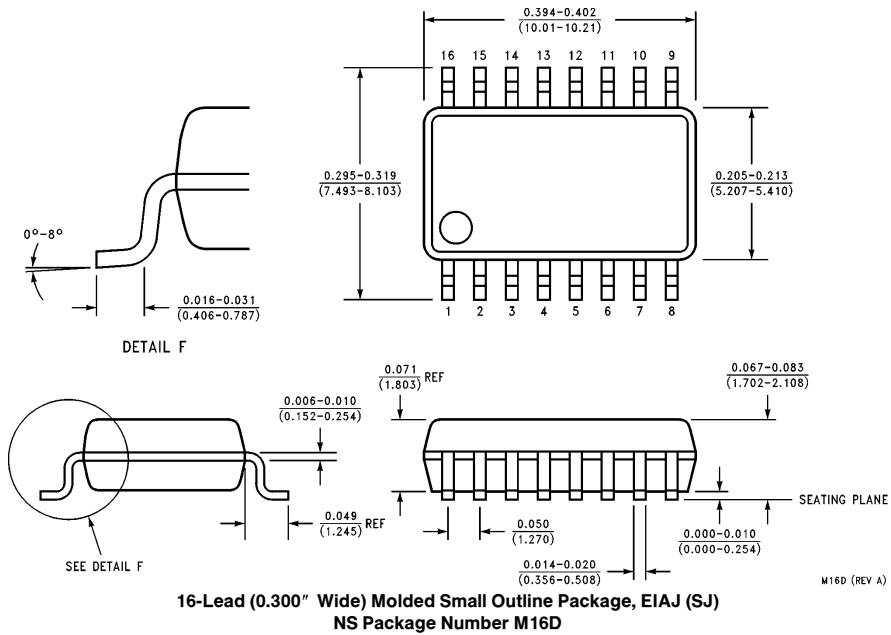


**16-Lead Ceramic Dual-In-Line Package (D)
NS Package Number J16A**

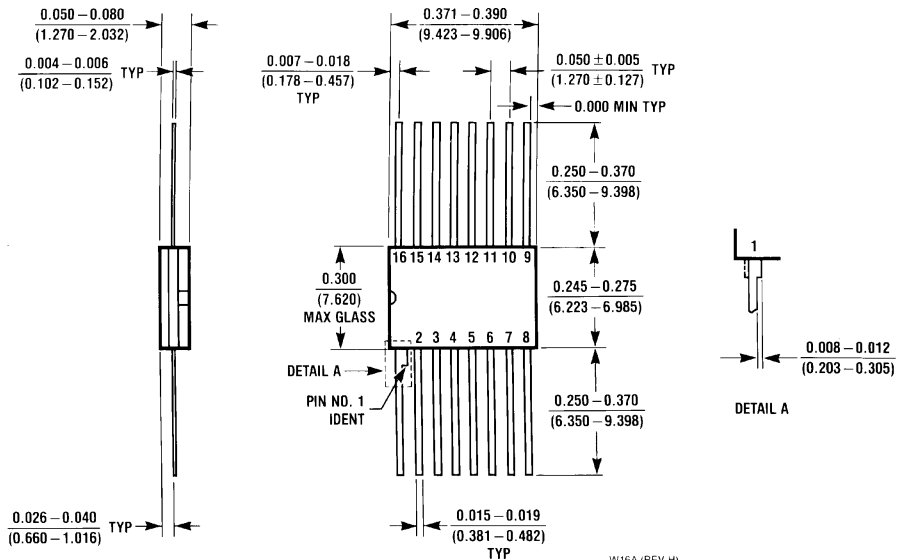


**16-Lead (0.150" Wide) Molded Small Outline Package, JEDEC (S)
NS Package Number M16A**

Physical Dimensions inches (millimeters) (Continued)



Physical Dimensions inches (millimeters) (Continued)



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